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Unipolar Hall Switch

High Precision Hall Effect Switch for 5 V Applications

TLI4965-5M

SP000930190

TLI4965-5M

Data Sheet

Revision 1.2, 2019-12-20

Sense & Control

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1 Product description

1.1 Overview

The TLI4965-5M is a high precision Hall effect unipolar switch with highly accurate switching thresholds for operating temperatures up to 125°C.

Characteristic	Supply Voltage	Supply Current	Sensitivity	Interface	Temperature
Unipolar Hall Effect Switch	3.0 V ~ 5.5 V	1.5 mA	High B_{OP}: 7.5 mT B_{RP}: 5 mT	Open Drain Output	-40°C to 125°C

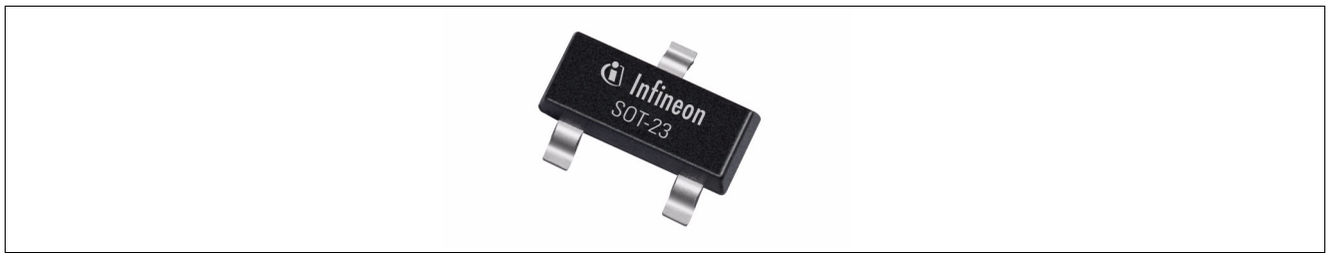


Figure 1 TLI4965-5M in the PG-SOT23-3-15 package

1.2 Features

- 3.0 V to 5.5 V operating supply voltage
- Operation from regulated power supply
- Active error compensation
- High stability of magnetic thresholds
- Low jitter (typ. 0.28 µs)
- 4 kV ESD (HBM) performance
- Small SMD package PG-SOT23-3-15
- For industrial and consumer applications, not qualified for automotive applications
  For automotive applications please refer to the Infineon TLE Hall Switches/Latches series

Table 1 Ordering information

Product name	Product type	Ordering code	Package
TLI4965-5M	Unipolar Hall Switch	SP000930190	PG-SOT23-3-15

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1.3 Target applications

Target applications for the TLI496x Hall Switch family are all applications which require a high precision Hall Switch with an operating temperature range from -40°C to 125°C.

The TLI4965-5M is a unipolar switch with a typical operating point B_{OP} = 7.5 mT and a hysteresis of B_{HYS} = 2.5 mT. It is ideally suited for various position detection applications, e.g. gear stick, steering lock or brake light.

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2 Functional description

2.1 General

The TLI4965-5M is an integrated Hall effect switch designed specifically for highly accurate applications where the sensor is connected to a regulated power supply voltage in the range of 3.0 V to 5.5 V. It provides a large operating temperature range and temperature stability of the magnetic thresholds.

2.2 Pin configuration (top view)

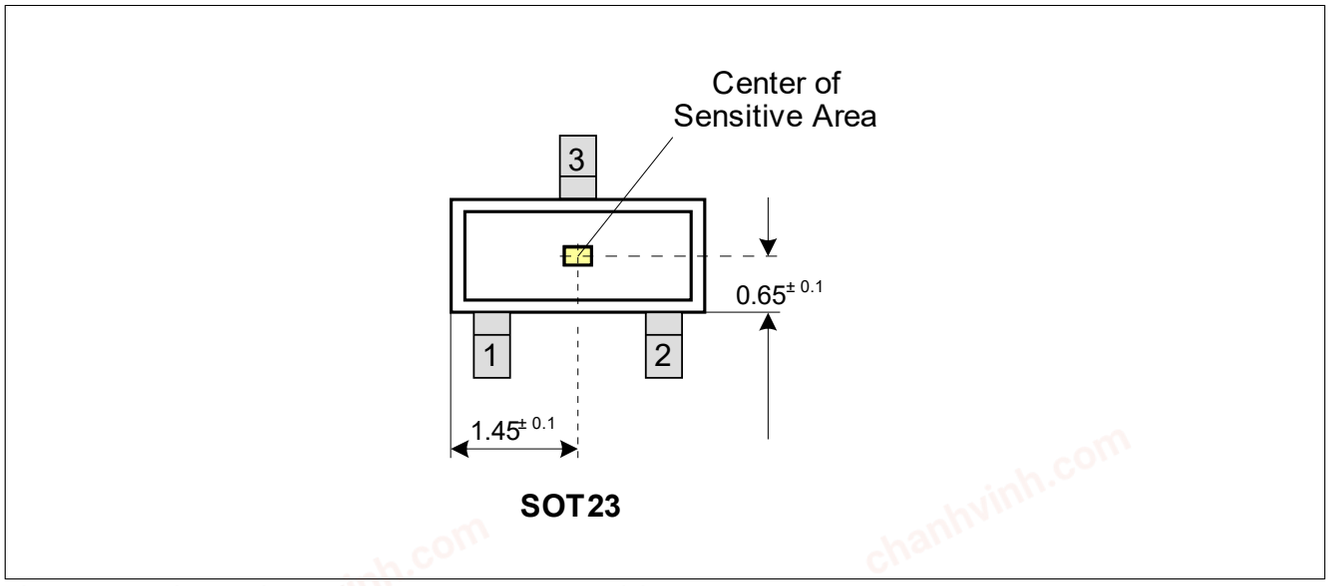


Figure 2 Pin configuration and center of sensitive area

2.3 Pin description

Table 2 Pin description PG-SOT23-3-15

Pin no.	Symbol	Function
1	VDD	Supply voltage
2	Q	Output
3	GND	Ground

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2.4 Block diagram

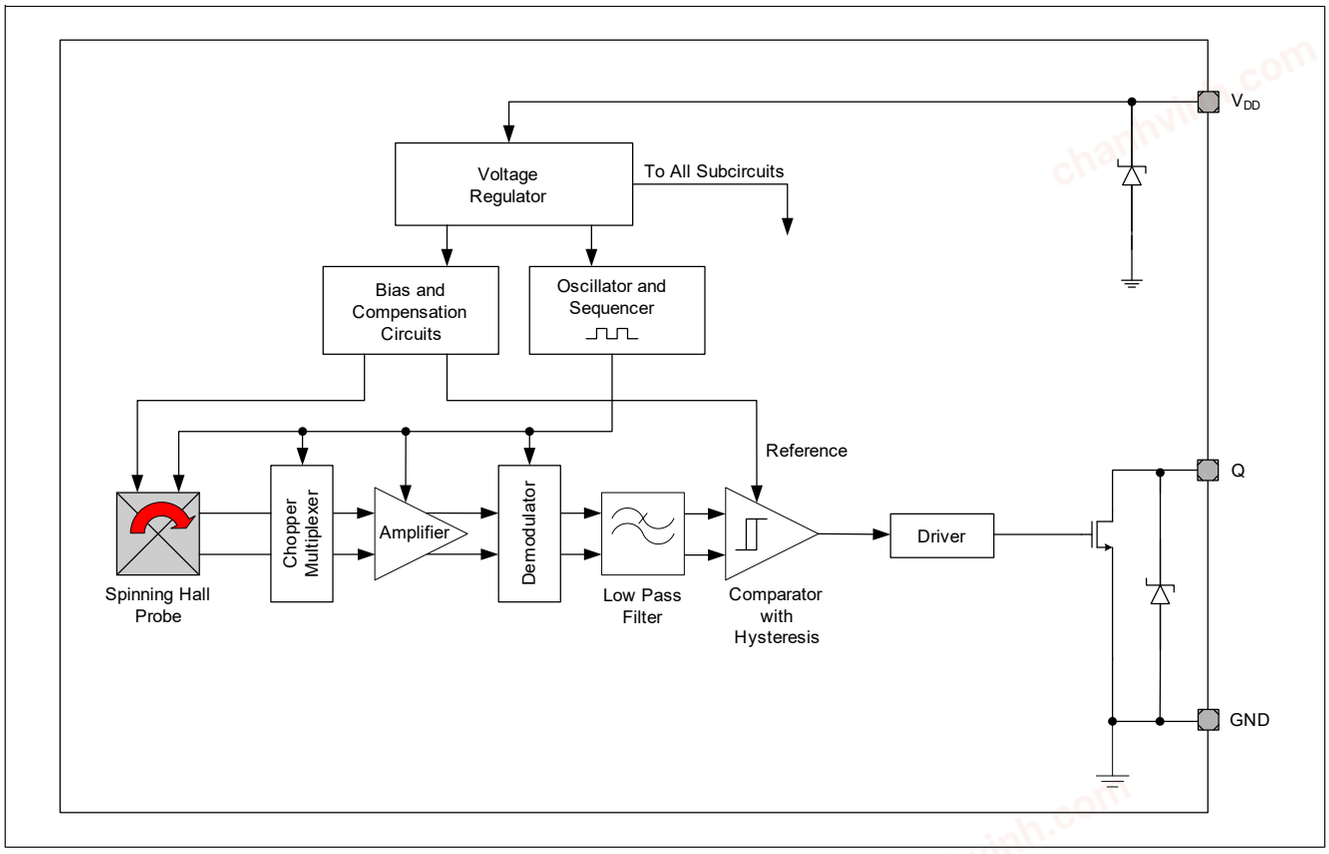


Figure 3 Functional block diagram TLI4965-5M

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2.5 Functional block description

The chopped Hall IC switch comprises a Hall probe, bias generator, compensation circuits, oscillator and output transistor.

The bias generator provides currents for the Hall probe and the active circuits. Compensation circuits stabilize the temperature behavior and reduce influence of technology variations.

The active error compensation (chopping technique) rejects offsets in the signal path and the influence of mechanical stress to the Hall probe caused by molding and soldering processes and other thermal stress in the package. The chopped measurement principle together with the threshold generator and the comparator ensures highly accurate and temperature stable magnetic thresholds.

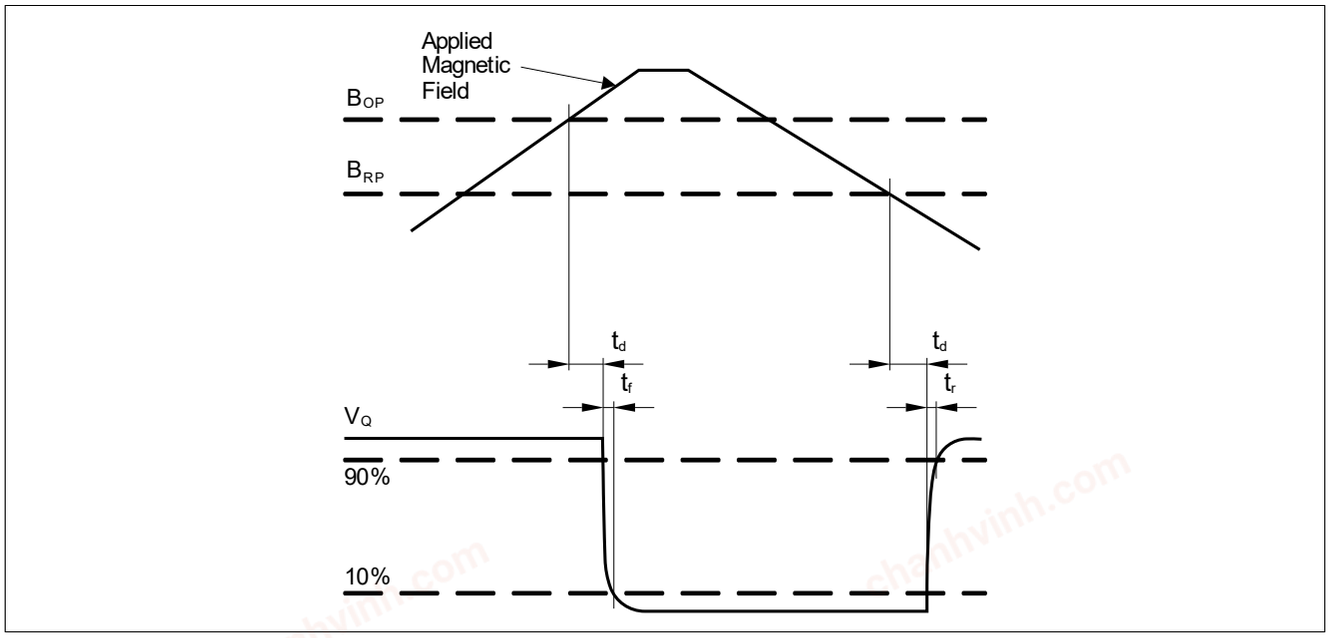


Figure 4 Timing diagram TLI4965-5M

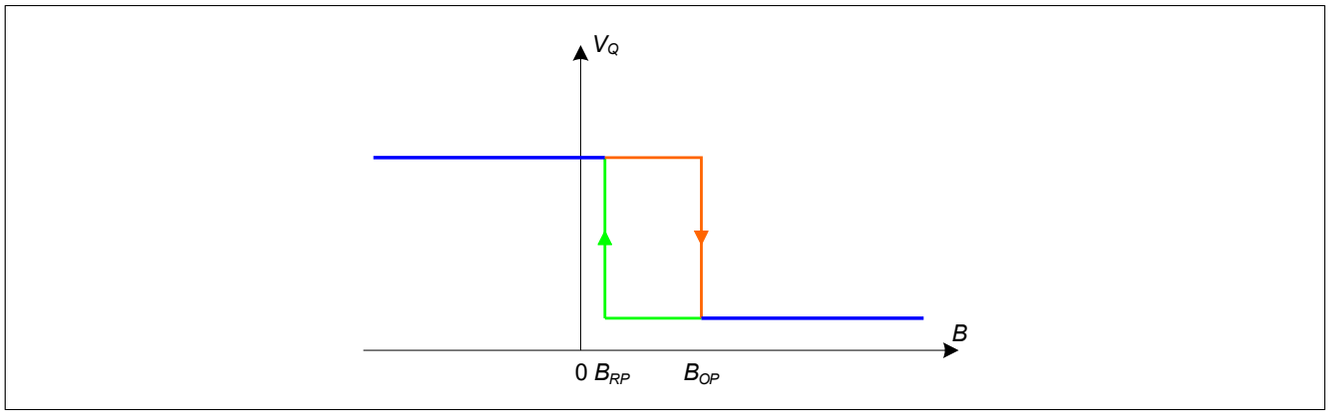


Figure 5 Output signal TLI4965-5M

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2.6 Default start-up behavior

The magnetic thresholds exhibit a hysteresis $B_{HYS} = B_{OP} - B_{RP}$. In case of a power-on with a magnetic field B within hysteresis ($B_{OP} > B > B_{RP}$) the output of the sensor is set to the pull up voltage level (V_Q) per default. After the first crossing of B_{OP} or B_{RP} of the magnetic field the internal decision logic is set to the corresponding magnetic input value.

V_{DDA} is the internal supply voltage which is following the external supply voltage V_{DD}.

This means for $B > B_{OP}$ the output is switching, for $B < B_{RP}$ and $B_{OP} > B > B_{RP}$ the output stays at V_Q.

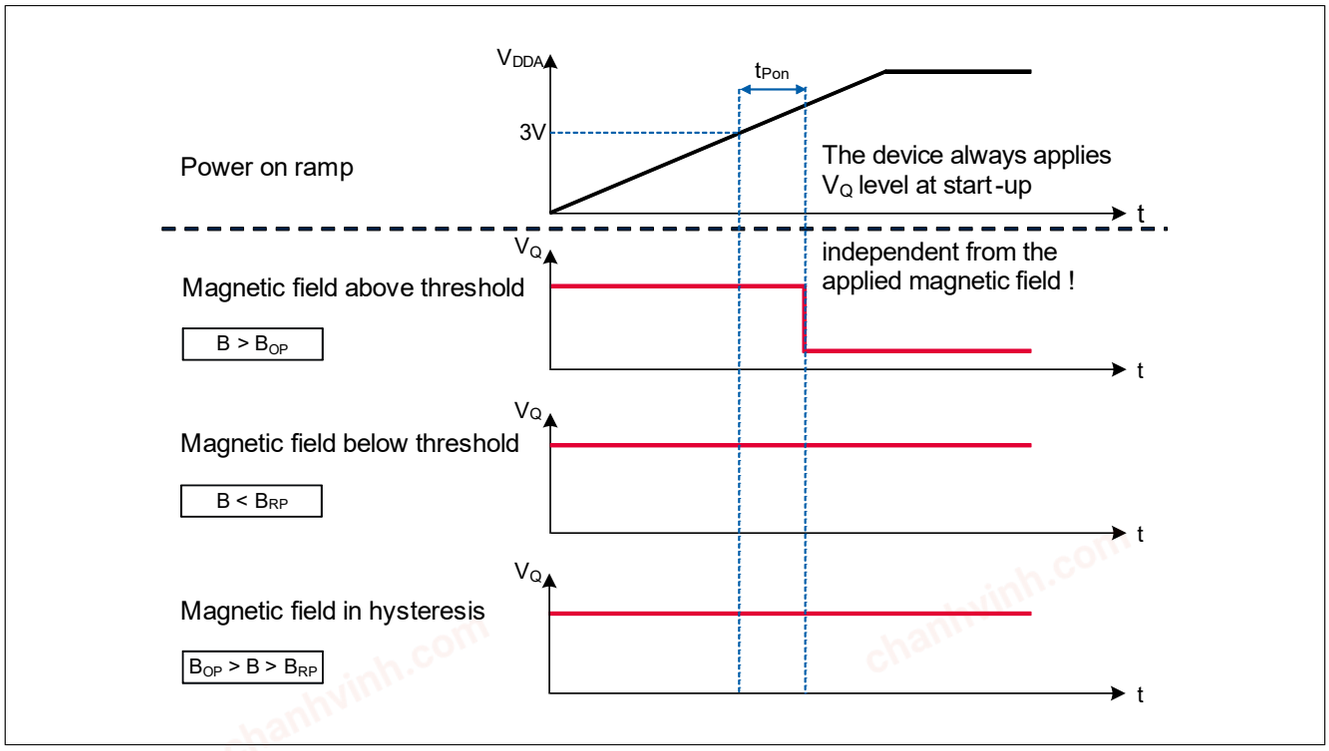


Figure 6 Start-up behavior of the TLI4965-5M

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3 Specification

3.1 Application circuit

The following **Figure 7** shows one option of an application circuit.

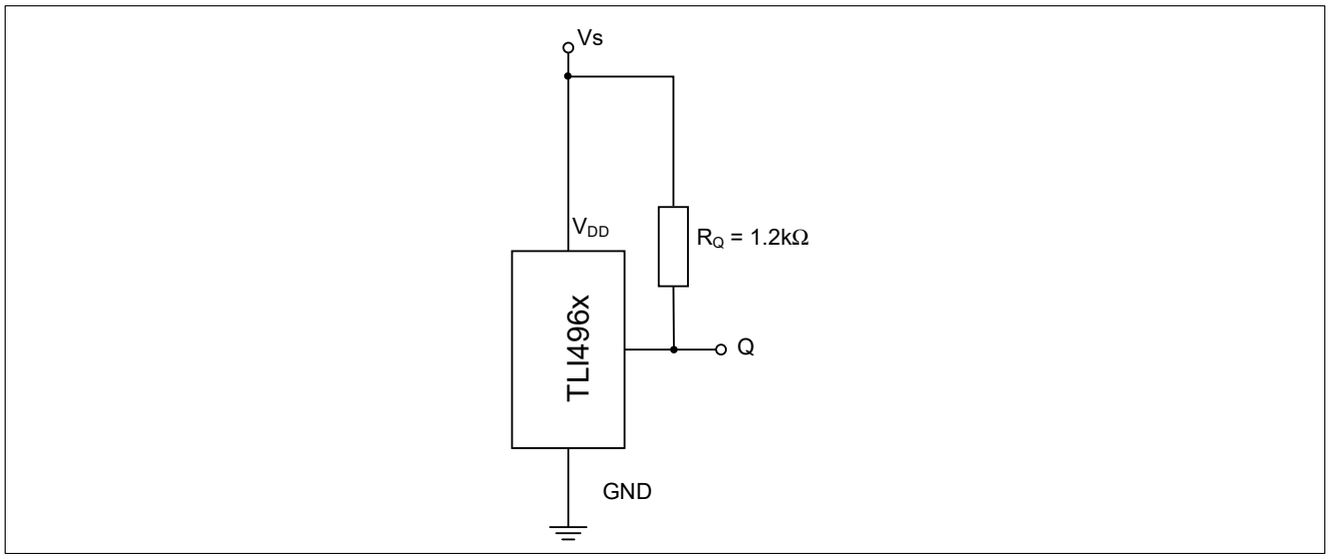


Figure 7 Application circuit

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3.2 Absolute maximum ratings

Table 3 Absolute maximum rating parameters

Parameter	Symbol	Values			Unit	Note or Test Condition
		Min.	Typ.	Max.		
Supply voltage[1)]	V_{DD}	-0.3	–	6	V	–
Output voltage	V_Q	-0.5	–	6	V	–
Ambient temperature[1)]	T_A	-40	–	150	°C	for 2000h (not additive)
Thermal resistance Junction ambient	R_{thJA}	–	–	300	K/W	for PG-SOT23-3-15 (2s2p)
Thermal resistance Junction lead	R_{thJL}	–	–	100	K/W	for PG-SOT23-3-15

1) This lifetime statement is an anticipation based on an extrapolation of Infineon's qualification test results. The actual lifetime of a component depends on its form of application and type of use etc. and may deviate from such statement. The lifetime statement shall in no event extend the agreed warranty period.

Attention: Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit.

Calculation of the dissipated power P_{DIS} and junction temperature T_J of the chip (SOT23 example):
e.g. for: V_{DD} = 5 V, I_S = 2 mA, V_{QSAT} = 0.5 V, I_Q = 1 mA
Power dissipation: P_{DIS} = 5 V x 2 mA + 0.5 V x 1 mA = 10 mW + 0.5 mW = 10.5 mW
Temperature $\Delta T = R_{thJA} \times P_{DIS}$ = 300 K/W x 10.5 mW = 3.15 K
For T_A = 150°C: $T_J = T_A + \Delta T$ = 150°C + 3.15 K = 153.15°C

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Table 4 ESD protection[1] (T_A = 25°C)

Parameter	Symbol	Values			Unit	Note or Test Condition
		Min.	Typ.	Max.		
ESD voltage (HBM)[2]	V_{ESD}	-4	–	4	kV	R = 1.5 kΩ, C = 100 pF
ESD voltage (CDM)[3]	V_{ESD}	-1	–	1	kV	–

1) Characterization of ESD is carried out on a sample basis, not subject to production test.
2) Human Body Model (HBM) tests according to ANSI/ESDA/JEDEC JS-001.
3) Charge device model (CDM) tests according to JESD22-C101.

3.3 Operating range

The following operating conditions must not be exceeded in order to ensure correct operation of the TLI4965-5M.

All parameters specified in the following sections refer to these operating conditions unless otherwise mentioned.

The maximum tested magnetic field is 600 mT.

Table 5 Operating conditions parameters

Parameter	Symbol	Values			Unit	Note or Test Condition
		Min.	Typ.	Max.		
Supply voltage	V_{DD}	3.0	–	5.5	V	–
Output voltage	V_Q	-0.3	–	5.5	V	–
Ambient temperature	T_A	-40	–	125	°C	–
Output current	I_Q	0	–	5	mA	–
Magnetic signal input frequency[1]	f_{SW}	0	–	10	kHz	–

1) For operation at the maximum switching frequency the magnetic input signal must be 1.4 times higher than for static fields.This is due to the -3 dB corner frequency of the internal low-pass filter in the signal path.

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3.4 Electrical and magnetic characteristics

Product characteristics involve the spread of values guaranteed within the specified voltage and ambient temperature range. Typical characteristics are the median of the production and correspond to V_{DD} = 5 V and T_A = 25°C. The below listed specification is valid in combination with the application circuit shown in **Figure 7**.

Table 6 General electrical characteristics

Parameter	Symbol	Values			Unit	Note or Test Condition
		Min.	Typ.	Max.		
Supply current	I_S	1.1	1.5	2.5	mA	–
Reverse current[1)]	I_{SR}	–	–	2.5	mA	for V_{DD} = -0.3 V and 125°C
Output saturation voltage	V_{QSAT}	–	0.2	0.5	V	I_Q = 5 mA
Output leakage current	I_{QLEAK}	–	–	10	µA	–
Output fall time[1)]	t_f	0.17	0.24	1	µs	1.2 kΩ / 50 pF, see **Figure 4**
Output rise time[1)]	t_r	0.4	0.5	1	µs	1.2 kΩ / 50 pF, see **Figure 4**
Output jitter[1)2)]	t_{QJ}	–	0.28	1	µs	for square wave signal with 1 kHz
Delay time[1)3)]	t_d	11.5	15	30	µs	see **Figure 4**
Power-on time[1)4)]	t_{PON}	–	50	100	µs	V_{DD} = 3 V, $B \le B_{RP}$ - 0.5 mT or $B \ge B_{OP}$ + 0.5 mT
Chopper frequency[1)]	f_{OSC}	–	350		kHz	–

1) Not subject to production test, verified by design/characterization.
2) Output jitter is the 1 σ value of the output switching distribution.
3) Systematic delay between magnetic threshold reached and output switching.
4) Time from applying V_{DD} = 3.0 V to the sensor until the output is valid.

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Table 7 Magnetic characteristics

Parameter	Symbol	T (°C)	Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
Operating point	B_{OP}	-40	5.4	8.5	11.6	mT	–
		25	4.6	7.5	10.4		
		125	3.5	6.0	8.5		
Release point	B_{RP}	-40	3.2	5.7	8.1	mT	–
		25	2.8	5.0	7.3		
		125	2.0	4.0	6.0		
Hysteresis	B_{HYS}	-40	1.5	2.8	4.1	mT	–
		25	1.3	2.5	3.7		
		125	1.1	2.0	2.9		
Effective noise value of the magnetic switching points[1)2)]	B_{Neff}	25	–	39	–	µT	–
Temperature compensation of magnetic thresholds[2)]	T_C	–	–	-2000	–	ppm/K	–

1) The magnetic noise is normal distributed and can be assumed as nearly independent to frequency without sampling noise or digital noise effects. The typical value represents the rms-value and corresponds therefore to a 1 σ probability of normal distribution. Consequently a 3 σ value corresponds to 0.3% probability of appearance.

2) Not subject to production test, verified by design/characterization.

Field direction definition

Positive magnetic fields are defined with the south pole of the magnet to the branded side of package.

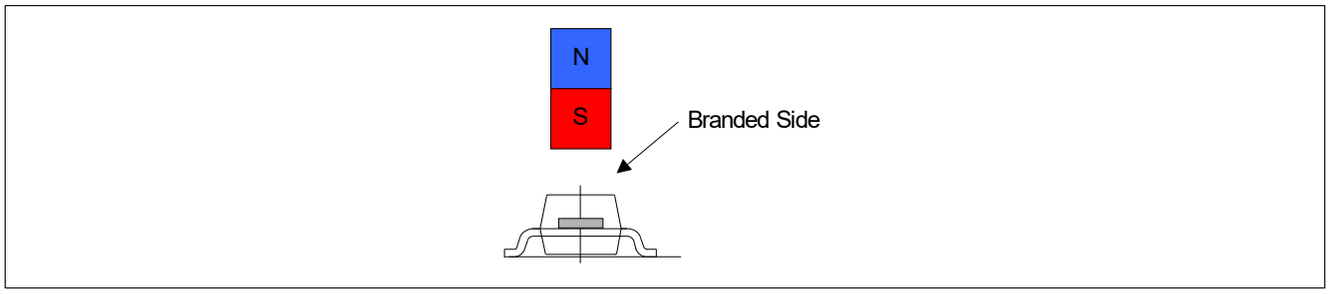


Figure 8 Definition of magnetic field direction PG-SOT23-3-15

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4 Package information

The TLI4965-5M is available in the small halogen-free SMD package PG-SOT23-3-15.

4.1 Package outline PG-SOT23-3-15

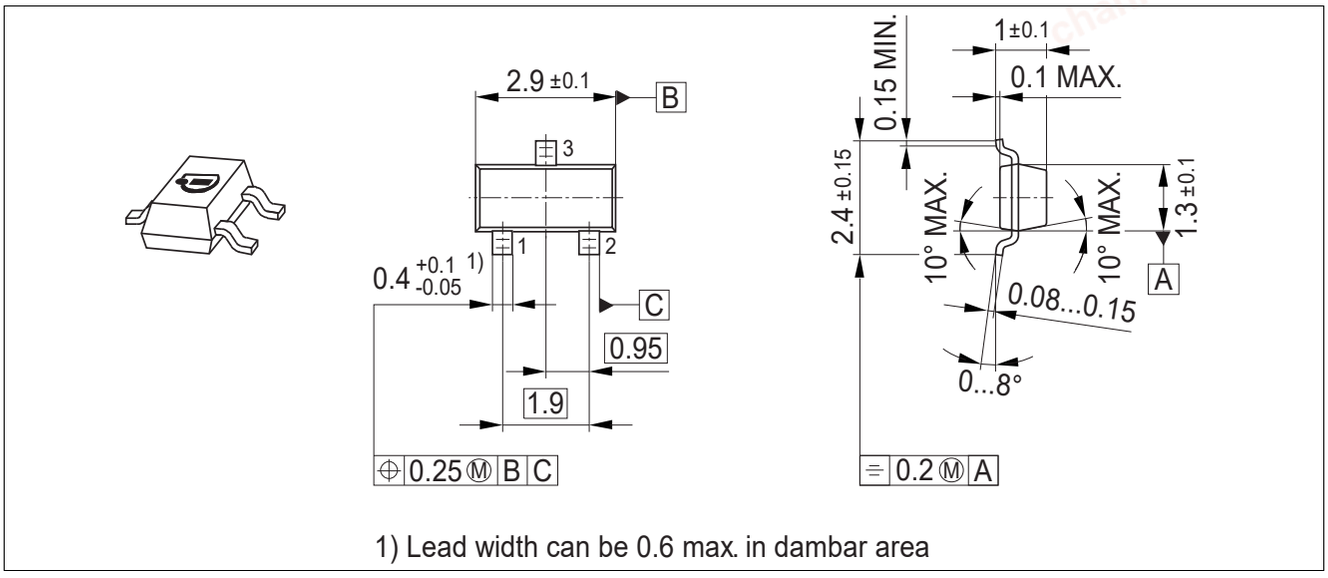


Figure 9 PG-SOT23-3-15 package outline (all dimensions in mm)

4.2 Packing information PG-SOT23-3-15

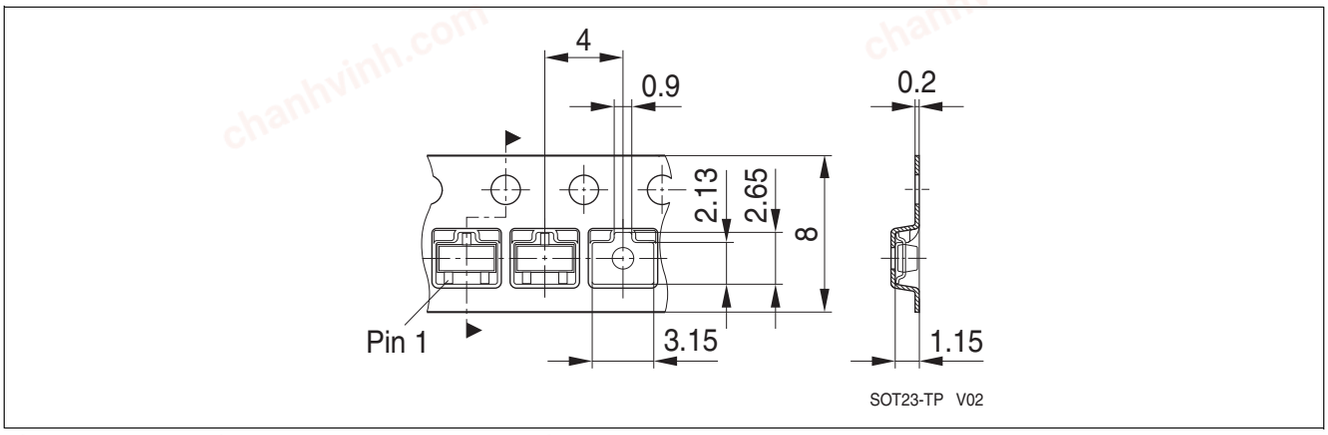


Figure 10 Packing of the PG-SOT23-3-15 in a tape

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4.3 Footprint PG-SOT23-3-15

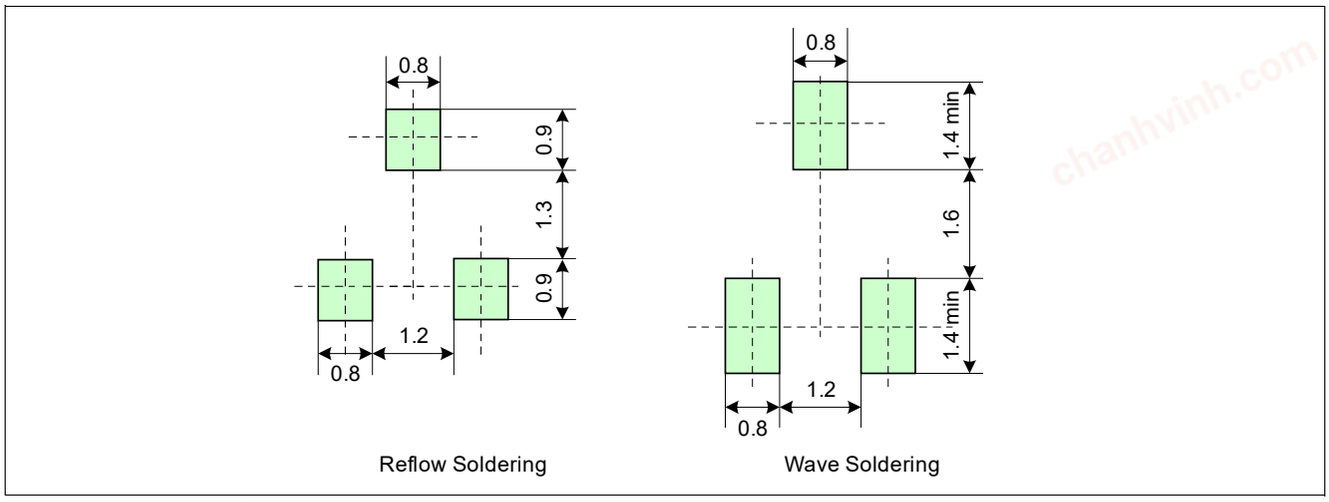


Figure 11 Footprint PG-SOT23-3-15

4.4 PG-SOT23-3-15 distance between chip and package

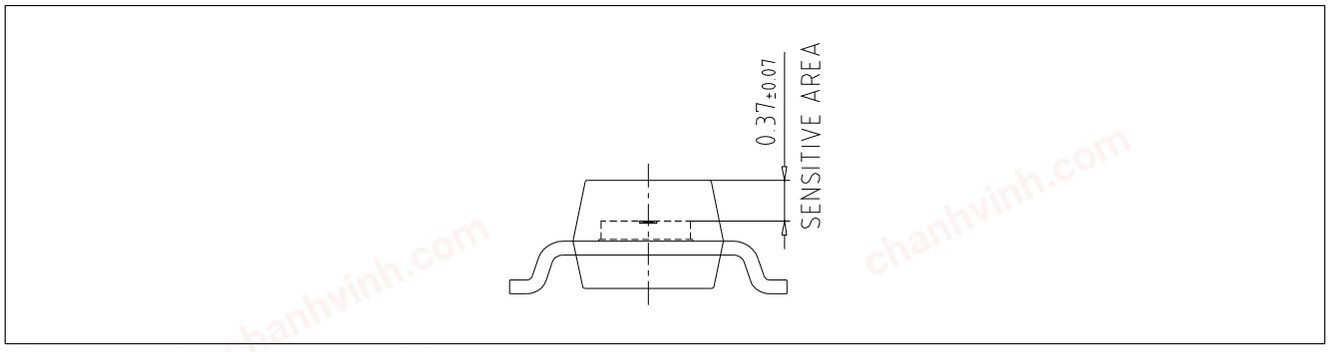


Figure 12 Distance between chip and package

4.5 Package marking

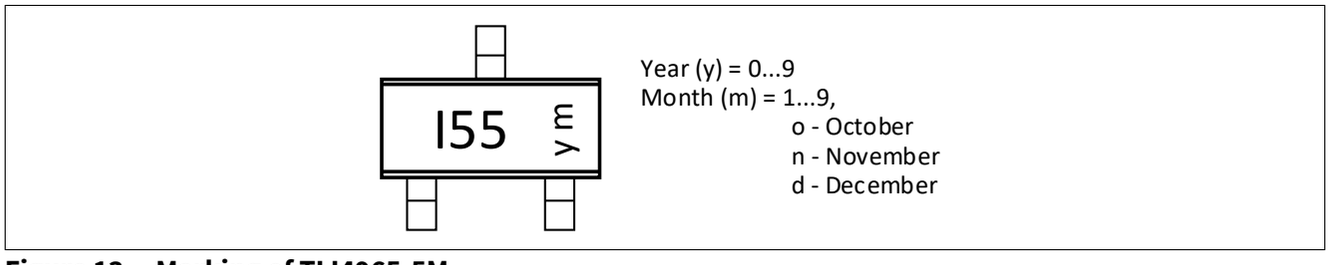


Figure 13 Marking of TLI4965-5M

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5 Revision history

Revision	Date	Changes
Revision 1.2	2019-12-20	Updated text and figure in **Chapter 2.6** Updated standards in **Table 4** Added maximum tested magnetic field in **Chapter 3.3** Updated **Figure 12** Editorial changes
Revision 1.0	2016-01-11	Initial release

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